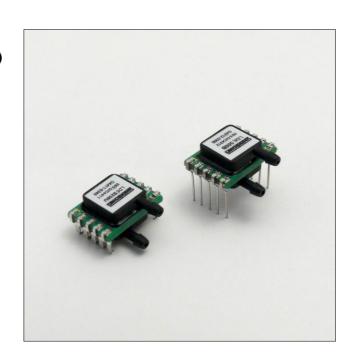
FEATURES

- Pressure ranges from 25 to 500 Pa (0.1 to 2 inH₂O)
- Pressure sensor based on thermal micro-flow measurement
- · High flow impedance
 - → very low flow-through leakage
 - → high immunity to dust and humidity
 - → no loss in sensitivity using long tubing
- Calibrated and temperature compensated
- Unique offset autozeroing feature ensuring superb long-term stability
- Offset accuracy better than 0.2 %FS
- Total accuracy better than 0.5 %FS typical
- · On-chip temperature sensor
- · Analog output and digital SPI interface
- · No position sensitivity
- · RoHS and REACH compliant
- Quality Management System according to EN ISO 13485 and EN ISO 9001



MEDIA COMPATIBILITY

Air and other non-corrosive gases

SPECIFICATIONS

Maximum ratings

Soldering recommendations

Reflow soldering, peak temperature 235...245 °C Wave soldering, pot temperature 260 °C Hand soldering, tip temperature 370...425 °C

Temperature ranges

 Compensated
 0 ... +70 °C

 Operating
 -20 ... +80 °C

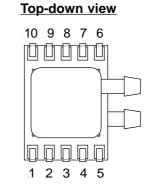
 Storage
 -40 ... +80 °C

Humidity limits (non-condensing) 97 %RH

Vibration¹ 20 g

Mechanical shock² 500 g

ELECTRICAL CONNECTION3



Pin	Function			
1	Reserved			
2	Vs			
3	GND			
4	Vout			
5	Vout			
6	SCLK			
7	MOSI			
8	MISO			
9	/CS			
10	Reserved			

There are three use cases that will change the manner in which the LDE sensor is connected in-circuit. For detailed pin connections see page 12.

Specification notes:

- 1. Sweep 20 to 2000 Hz, 8 min, 4 cycles per axis, MIL-STD-883, Method 2007.
- 2. 5 shocks, 3 axes, MIL-STD-883E, Method 2002.4.
- 3. The maximum voltage applied to pin 1 and pins 6 through 10 should not exceed V_s +0.3 V.

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PRESSURE SENSOR CHARACTERISTICS

Part no.	Operating pressure	Proof pressure ⁴	Burst pressure ⁴
LDES025U	025 Pa / 00.25 mbar (0.1 inH ₂ O)		
LDES050U	050 Pa / 00.5 mbar (0.2 inH ₂ O)		
LDES100U	0100 Pa / 01 mbar (0.4 inH ₂ O)		
LDES250U	0250 Pa / 02.5 mbar (1 inH ₂ O)		
LDES500U	0500 Pa / 05 mbar (2 inH ₂ O)	2 bar	5 bar
LDES025B	0±25 Pa / 0±0.25 mbar (±0.1 inH ₂ O)	(30 psi)	(75 psi)
LDES050B	0±50 Pa / 0±0.5 mbar (±0.2 inH ₂ O)		
LDES100B	0±100 Pa / 0±1 mbar (±0.4 inH ₂ O)		
LDES250B	0±250 Pa / 0±2.5 mbar (±1 inH ₂ O)		
LDES500B	0±500 Pa / 0±5 mbar (±2 inH ₂ O)		

GAS CORRECTION FACTORS⁵

Gas type	Correction factor
Dry air	1.0
Oxygen (O ₂)	1.07
Nitrogen (N ₂)	0.97
Argon (Ar)	0.98
Carbon dioxide (CO ₂)	0.56

Specification notes:

4. The max. common mode pressure is 5 bar.

5. For example with a LDES500... sensor measuring CO₂ gas, at full-scale output the actual pressure will be 500 Pa x 0.56 = 280 Pa.

 $\Delta P_{eff} = \Delta P_{sensor} \times gas$ correction factor

 ΔP_{eff} = True differential pressure

 $\Delta P_{\mbox{\tiny sensor}}$ = Differential pressure as indicated by output voltage

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PERFORMANCE CHARACTERISTICS

LDE...6...

 $(V_s = 5.0 V_{DC}, T_A = 20 °C, P_{Abs} = 1 bara, calibrated in air, output signals analog and digital are <u>non-ratiometric</u> to <math>V_s)$

all 25 Pa and 50 Pa devices

Characteristics	Min.	Тур.	Max.	Unit
Noise level (RMS)		±0.01		Pa
Offset warm-up shift			less than noise	
Offset long term stability ⁷		±0.05	±0.1	Pa/year
Offset repeatability		±0.01		Pa
Span repeatability ^{10, 11}		±0.25		% of reading
Current consumption (no load)8		7	8	mA
Response time (t ₆₃)		5		m.a
Power-on time			25	ms

Digital output

Characteristics			Min.	Тур.	Max.	Unit
Scale factor (digital out	put) ⁹	025 / 0±25 Pa		1200		counts/Pa
		050 / 0±50 Pa		600		Counts/Pa
Zero pressure offset accuracy ¹⁰				±0.1	±0.2	%FSS
Span accuracy ^{10, 11}				±0.4	±0.75	% of reading
Thermal effects	Offset	555 °C			±0.2	%FSS
		070 °C			±0.4	%F33
	Span	555 °C		±1	±1.75	0/ of roading
		070 °C		±2	±2.75	% of reading

Analog output (unidirectional devices)

Cl	naracteristics		Min.	Тур.	Max.	Unit
Zero pressure offset	Zero pressure offset			0.50	0.51	\/
Full scale output				4.50		V
Span accuracy ^{10, 11}				±0.4	±0.75	% of reading
Thermal effects	Offset	555 °C			±15	mV
		070 °C			±30	IIIV
	Span	555 °C		±1.25	±2	% of reading
		070 °C		±2	±2.75	% or reading

Analog output (bidirectional devices)

Characteristics			Min.	Тур.	Max.	Unit
Zero pressure offset			2.49	2.50	2.51	
Output	at max. spe	ecified pressure		4.50		V
	at min. spe	at min. specified pressure		0.50		
Span accuracy ^{10, 11}				±0.4	±0.75	% of reading
Thermal effects	Offset	555 °C			±15	mV
		070 °C			±30	mv
	Span	555 °C		±1.25	±2	0/ of roading
		070 °C		±2	±2.75	% of reading

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PERFORMANCE CHARACTERISTICS⁶ LDE...6...

 $(V_s = 5.0 V_{DC}, T_A = 20 °C, P_{Abs} = 1 bara, calibrated in air, output signals analog and digital are <u>non-ratiometric</u> to <math>V_s)$

all 100 Pa, 250 Pa and 500 Pa devices

Characteristics	Min.	Тур.	Max.	Unit
Noise level (RMS)		±0.01		%FSS
Offset warm-up shift			less than noise	
Offset long term stability ⁷		±0.05	±0.1	%FSS/year
Offset repeatability ¹²		±0.02		Pa
Span repeatability ^{10, 11}		±0.25		% of reading
Current consumption (no load)8		7	8	mA
Response time (t ₆₃)		5		
Power-on time			25	ms

Digital output

Characteristics			Min.	Тур.	Max.	Unit
Scale factor (digita	l output)9	0100 / 0±100 Pa		300		counts/Pa
		0250 / 0±250 Pa		120		Counts/Pa
		0500 / 0±500 Pa		60		
Zero pressure offset accuracy ¹⁰				±0.05	±0.1	%FSS
Span accuracy ^{10, 11}				±0.4	±0.75	% of reading
Thermal effects	Thermal effects Offset				±0.1	%FSS
		070 °C			±0.2	70F33
	Span	555 °C		±1	±1.75	% of reading
		070 °C		±2	±2.75	% or reading

Analog output (unidirectional devices)

Characteristics			Min.	Тур.	Max.	Unit
Zero pressure offset	Zero pressure offset			0.50	0.51	\/
Full scale output				4.50		V
Span accuracy ^{10, 11}				±0.4	±0.75	% of reading
Thermal effects	Offset	555 °C			±10	
		070 °C			±12	mV
	Span	555 °C		±1	±1.75	0/ of roading
	-	070 °C		±2	±2.75	% of reading

Analog output (bidirectional devices)

Characteristics			Min.	Тур.	Max.	Unit
Zero pressure offset			2.49	2.50	2.51	
Output	at max. sp	ecified pressure		4.50		V
	at min. specified pressure			0.50		
Span accuracy ^{10, 11}				±0.4	±0.75	% of reading
Thermal effects	Offset	555 °C			±10	mV
	070 °C		±12	IIIV		
	Span	555 °C		±1	±1.75	% of reading
		070 °C		±2	±2.75	% or reading

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PERFORMANCE CHARACTERISTICS⁶

LDE...3...

 $(V_s=3.0\ V_{DC}, T_A=20\ ^{\circ}C, P_{Abs}=1\ bara, calibrated in air, output signals analog and digital are <u>non-ratiometric</u> to <math>V_s)$

all 25 Pa and 50 Pa devices

Characteristics	Min.	Тур.	Max.	Unit
Noise level (RMS)		±0.01		Pa
Offset warm-up shift			less than noise	
Offset long term stability ⁷		±0.05	±0.1	Pa/year
Offset repeatability		±0.01		Pa
Span repeatability ^{10, 11}		±0.25		% of reading
Current consumption (no load)8		14	16	mA
Response time (t ₆₃)		5		ma
Power-on time			25	ms

Digital output

Ch	Characteristics			Тур.	Max.	Unit	
Scale factor (digital output)9		025 / 0±25 Pa		1200		counts/Pa	
		050 / 0±50 Pa		600		Counts/Pa	
Zero pressure offset accuracy ¹⁰			±0.1	±0.2	%FSS		
Span accuracy ^{10, 11}	-			±0.4	±0.75	% of reading	
Thermal effects	Offset	555 °C			±0.2	0/ 500	
		070 °C			±0.4	%FSS	
	Span 555 °C ±1 ±1.		±1.75	0/ of roading			
21 2		070 °C		±2	±2.75	% of reading	

Analog output (unidirectional devices)

Cl	naracteristics		Min.	Тур.	Max.	Unit	
Zero pressure offset	Zero pressure offset			0.30	0.31	\/	
Full scale output				2.70		V	
Span accuracy ^{10, 11}				±0.4	±0.75	% of reading	
Thermal effects	Offset	555 °C			±15	m)/	
		070 °C			±30	mV	
	Span	555 °C		±1.25	±2		
		070 °C		±2	±2.75	% of reading	

Analog output (bidirectional devices)

Characteristics			Min.	Тур.	Max.	Unit	
Zero pressure offset			1.49	1.50	1.51		
Output at max. specified pressure			2.70		V		
	at min. spe	at min. specified pressure		0.30			
Span accuracy ^{10, 11}				±0.4	±0.75	% of reading	
Thermal effects	rmal effects Offset 555 °C				±15	mV	
		070 °C			±30	TIIV	
	Span	555 °C		±1.25	±2	0/ of roading	
		070 °C		±2	±2.75	% of reading	

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PERFORMANCE CHARACTERISTICS⁶

LDE...3...

 $(V_s=3.0\ V_{DC}, T_A=20\ ^{\circ}C, P_{Abs}=1\ bara, calibrated in air, output signals analog and digital are <u>non-ratiometric</u> to <math>V_s)$

all 100 Pa, 250 Pa and 500 Pa devices

Characteristics	Min.	Тур.	Max.	Unit
Noise level (RMS)		±0.01		%FSS
Offset warm-up shift			less than noise	
Offset long term stability ⁷		±0.05	±0.1	%FSS/year
Offset repeatability ¹²		±0.02		Pa
Span repeatability ^{10, 11}		±0.25		% of reading
Current consumption (no load)8		14	16	mA
Response time (t ₆₃)		5		
Power-on time			25	ms

Digital output

Characteristics			Min.	Тур.	Max.	Unit
Scale factor (digita	l output)9	0100 / 0±100 Pa		300		counts/Pa
		0250 / 0±250 Pa		120		Counts/Pa
		0500 / 0±500 Pa		60		
Zero pressure offse	Zero pressure offset accuracy ¹⁰			±0.05	±0.1	%FSS
Span accuracy ^{10, 11}				±0.4	±0.75	% of reading
Thermal effects	Offset	555 °C			±0.1	%FSS
		070 °C			±0.2	70533
Span		555 °C		±1	±1.75	0/ of roading
		070 °C		±2	±2.75	% of reading

Analog output (unidirectional devices)

Characteristics			Min.	Тур.	Max.	Unit
Zero pressure offset			0.29	0.30	0.31	1/
Full scale output				2.70		V
Span accuracy ^{10, 11}				±0.4	±0.75	% of reading
Thermal effects					±10	
		070 °C			±12	mV
	Span	555 °C ±1 ±1		±1.75	0/ of roading	
	·	070 °C		±2	±2.75	% of reading

Analog output (bidirectional devices)

Amaiog output (biamostional dovidos)									
Characteristics			Min.	Тур.	Max.	Unit			
Zero pressure offset			1.49	1.50	1.51				
Output at max. specified pressure			2.70		V				
	at min. spe	at min. specified pressure		0.30					
Span accuracy ^{10, 11}				±0.4	±0.75	% of reading			
Thermal effects	Offset	555 °C			±10	mV			
		070 °C			±12	IIIV			
	Span	Span 555 °C ±1		±1.75	% of reading				
		070 °C		±2	±2.75	% or reading			

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PERFORMANCE CHARACTERISTICS

Temperature sensor

Characteristics	Min.	Тур.	Max.	Unit
Scale factor (digital output)		95		counts/°C
Non-linearity		±0.5		0/ EC
Hysteresis		±0.1		%FS

Total accuracy¹³

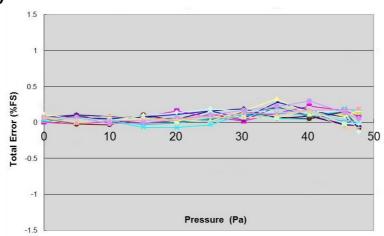


Fig. 1: Typical total accuracy plot of 16 LDE 50 Pa sensors @ 25 °C (typical total accuracy better than 0.5 %FS)

Offset long term stability

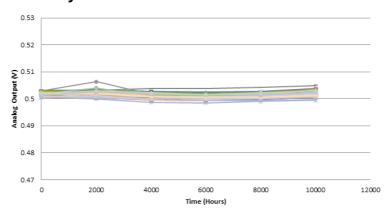


Fig. 2: Offset long term stability for LDE 250 Pa sensors after 10 000 hours @ 85°C powered, equivalent to over 43.5 years @ 25 °C (better than ±2 mV / ±0.125 Pa)

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SPI - SERIAL PERIPHERAL INTERFACE

Note: It is important to adhere to the communication protocol in order to avoid damage to the sensor.

Introduction

The LDE serial interface is a high-speed synchronous data input and output communication port. The serial interface operates using a standard 4-wire SPI bus. The LDE device runs in SPI mode 0, which requires the clock line SCLK to idle low (CPOL = 0), and for data to be sampled on the leading clock edge (CPHA = 0). Figure 5 illustrates this mode of operation.

Care should be taken to ensure that the sensor is properly connected to the master microcontroller. Refer to the manufacturer's datasheet for more information regarding physical connections.

Application circuit

The use of pull-up resistors is generally unnecessary for SPI as most master devices are configured for push-pull mode. If pull-up resistors are required for use with 3 V LDE devices, however, they should be greater than 50 k Ω .

There are, however, some cases where it may be helpful to use 33Ω series resistors at both ends of the SPI lines, as shown in Figure 3. Signal quality may be further improved by the addition of a buffer as shown in Figure 4. These cases include multiple slave devices on the same bus segment, using a master device with limited driving capability and long SPI bus lines.

If these series resistors are used, they must be physically placed as close as possible to the pins of the master and slave devices.

Signal control

The serial interface is enabled by asserting /CS low. The serial input clock, SCLK, is gated internally to begin accepting the input data at MOSI, or sending the output data on MISO. When /CS rises, the data clocked into MOSI is loaded into an internal register.

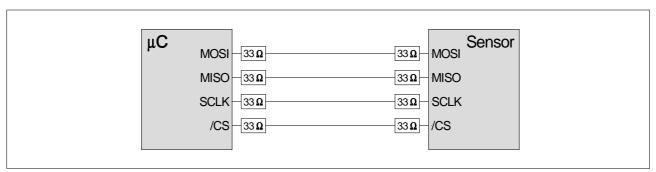


Fig. 3: Resistors at both ends of the SPI lines

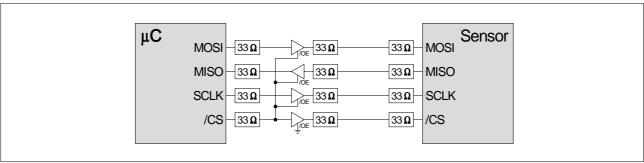


Fig. 4: Addition of a buffer

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SPI - SERIAL PERIPHERAL INTERFACE

Note: It is important to adhere to the communication protocol in order to avoid damage to the sensor.

Data read - pressure

When powered on, the sensor begins to continuously measure pressure. To initiate data transfer from the sensor, the following three unique bytes must be written sequentially, MSB first, to the MOSI pin (see Figure 5):

Step	ep Hexadecimal Binary		Description
1	0x2D	B00101101	Poll current pressure measurement
2	0x14	B00010100	Send result to data register
3	0x98	B10011000	Read data register

The entire 16 bit content of the LDE register is then read out on the MISO pin, MSB first, by applying 16 successive clock pulses to SCLK with /CS asserted low. Note that the value of the LSB is held at zero for internal signal processing purposes. This is below the noise threshold of the sensor and thus its fixed value does not affect sensor performance and accuracy.

From the digital sensor output the actual pressure value can be calculated as follows:

pressure
$$[Pa] = \frac{\text{digital output } [\text{counts}]}{\text{scale factor } \left[\frac{\text{counts}}{\text{Pa}}\right]}$$

For example, for a ±250 Pa sensor (LDES250B...) with a scale factor of 120 a digital output of 30 000 counts (7530'h) calculates to a positive pressure of 250 Pa. Similarly, a digital output of -30 000 counts (8AD0'h) calculates to a negative pressure of -250 Pa.

Data read - temperature

The on-chip temperature sensor changes 95 counts/°C over the operating range. The temperature data format is 15-bit plus sign in two's complement format. To read temperature, use the following sequence:

Step	Hexadecimal	Binary	Description
1	0x2A	B00101010	Poll current temperature measurement
2	0x14	B00010100	Send result to data register
3	0x98	B10011000	Read data register

From the digital sensor output, the actual temperature can be calculated as follows:

temperature [°C] =
$$\frac{\text{TS - TS}_0[\text{counts}]}{\text{scale factor}_{\text{TS}}[\text{counts}/\text{°C}]} + \text{T}_0[\text{°C}]$$

where

TS is the actual sensor readout;

 TS_0 is the sensor readout at known temperature T_0^{14} ; Scale factor_{TS} = 95 counts/°C

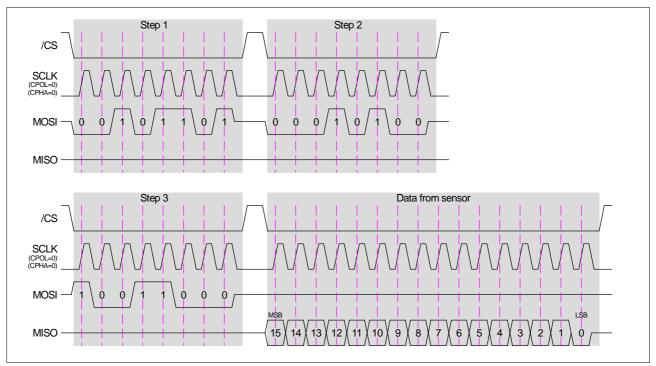


Fig. 5: SPI data transfer

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Interface specification

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
External clock frequency	f _{ECLK}	V _{CKSEL} =0 Min.		0.2		NALI-
		Max.		5		MHz
External master clock input low time	f _{ECLKIN LO}	t _{ECLK} =1/f _{ECLK}	40		60	0/+
External master clock input high time	f _{ECLKIN HI}	t _{ECLK} =1/f _{ECLK}	40		60	%t _{ECLK}
SCLK setup to falling edge /CS	t _{sc}		30			20
/CS falling edge to SCLK rising edge setup time	t _{css}		30			ns
/CS idle time	t _{csi}	f _{CLK} =4 MHz	1.5			μs
SCLK falling edge to data valid delay	t _{DO}	C _{LOAD} =15 pF			80	
Data valid to SCLK rising edge setup time	t _{DS}		30			
Data valid to SCLK rising edge hold time	t _{DH}		30			
SCLK high pulse width	t _{CH}		100			no
SCLK low pulse width	t _{CL}		100			ns
/CS rising edge to SCLK rising edge hold time	t _{CSH}		30			
/CS falling edge to output enable	t _{DV}	C _{LOAD} =15 pF			25	
/CS rising edge to output disable	t _{TR}	C _{LOAD} =15 pF			25	
LDE6 (5 V supply)						
Maximum output load capacitance	C _{LOAD}	R _{LOAD} =∞, phase margin >55°		200		pF
Input voltage, logic HIGH	V _{IH}		0.8×V _s		V _s +0.3	
Input voltage, logic LOW	V _L				0.2×V _s	
Output voltage, logic HIGH	V _{OH}	R _{LOAD} =∞	V _s -0.1			V
		$R_{LOAD} = 2 k\Omega$	V _s -0.15			v
Output voltage, logic LOW	V _{OL}	R _{LOAD} =∞			0.5	
		$R_{LOAD} = 2 k\Omega$			0.2	
LDE3 (3 V supply) ¹⁵						
Maximum output load capacitance	C _{LOAD}	$R_{LOAD} = 1 k\Omega$		15		pF
Input voltage, logic HIGH	V _{IH}		0.65×V _s		V _s +0.3	
Input voltage, logic LOW	V _L				0.35×V _s	V
Output voltage, logic HIGH	V _{OH}	l _o =-20 μA	V _s -0.4			v
Output voltage, logic LOW	V _{OL}	l _o =20 μA			0.4	

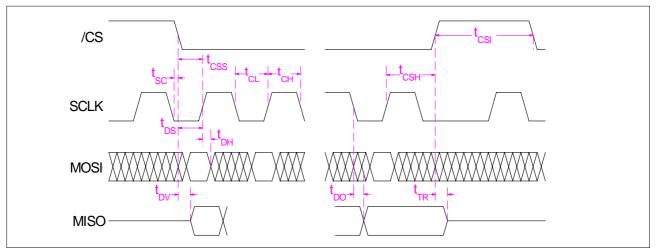


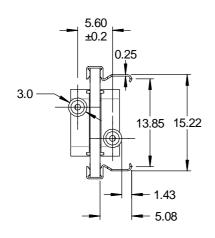
Fig. 5: Timing diagram

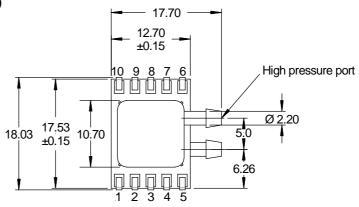
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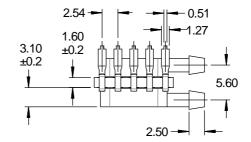


OUTLINE DRAWING

LDE...E... (SMD, 2 ports same side)

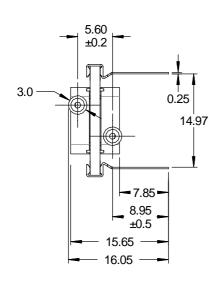


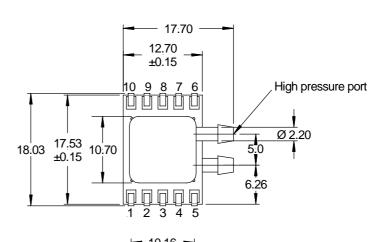


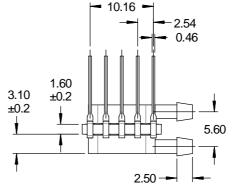


dimensions in mm all tolerances ±0.1 mm unless otherwise noted

LDE...F... (DIP, 2 ports same side)







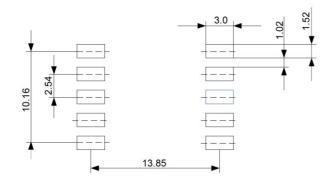
dimensions in mm all tolerances ±0.1 mm unless otherwise noted

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OUTLINE DRAWING

Sensor PCB footprint



dimensions in mm all tolerances ±0.1 mm unless otherwise noted

ELECTRICAL CONNECTION3

There are three use cases that will change the manner in which the LDE series device is connected in-circuit:

Case 1: Reading of pressure measurement as a digital (SPI) signal;

Case 2: Reading of pressure measurement as an analog (voltage) signal; and

Case 3: Pin-to-pin compatible drop-in replacement for LBA series devices (5 V LDE devices only).

The connections for each such use case must be made as indicated below.

			Connection	
Pin Function		Case 1: Digital signal output	Case 2: Analog signal output	Case 3: LBA drop-in replacement (5 V LDE only)
1	Reserved	NC	NC	GND
2	Vs	+5 V / +3 V	+5 V / +3 V	+5 V
3	GND	GND	GND	GND
4	Vout	NC	High-impedance analog input	High-impedance analog input
5	Vout	NC	(e.g. op-amp, ADC)	(e.g. op-amp, ADC)
6	SCLK	Master device SCLK	GND	GND
7	MOSI	Master device MOSI	GND	GND
8	MISO	Master device MISO	GND	GND
9	/CS	Master device (/CS)	Vs	GND
10	Reserved	NC	NC	GND

Digital low differential pressure sensors

Specification notes:

6. The sensor is calibrated with a common mode pressure of 1 bar absolute. Due to the mass flow based measuring principle, variations in absolute common mode pressure need to be compensated according to the following formula:

$$\Delta P_{eff} = \Delta P_{sensor} \times \frac{1 \text{bara}}{P_{abs}} \qquad \qquad \Delta P_{eff} = \text{True differential pressure} \\ \Delta P_{sensor} = \text{Differential pressure as indicated by output voltage} \\ \Delta P_{sensor} = \text{Current absolute common mode pressure}$$

- 7. Figure based on accelerated lifetime test of 10 000 hours at 85 °C biased burn-in.
- 8. Please contact First Sensor for low power options.
- 9. The digital output signal is a signed, two's complement integer. Negative pressures will result in a negative output.
- **10.** Zero pressure offset accuracy and span accuracy are uncorrelated uncertainties. They can be added according to the principles of error propagation.
- 11. Span accuracy below 10 % of full scale is limited by the intrinsic noise of the sensor.
- 12. Typical value for 250 Pa sensors.
- 13. Total accuracy is the combined error from offset and span calibration, non-linearity, repeatability and pressure hysteresis.
- 14. To be defined by user. The results show deviation in °C from the offset calibrated temperature
- 15. For correct operation of LDE...3... devices, the device driving the SPI bus must have a minimum drive capability of ±2 mA.

ORDERING INFORMATION

	Series	Pressure range		Calibration		Housing		Output		Grade	
Options	LDE	S025	25 Pa	В	Bidirectional	Е	SMT, 2 ports	3	non-ratiometric,	S	High
			(0.1 inH ₂ O)	U	Unidirectional		same side		3 V supply		
		S050	50 Pa (0.2 inH ₂ O)			F	DIP, 2 ports same side	6	non-ratiometric, 5 V supply		
		S100	100 Pa (0.4 inH ₂ O)								
		S250	250 Pa (1 inH ₂ O)								
		S500	500 Pa (2 inH ₂ O)								
Example:	LDE	S250		В		F		6		S	

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